MODELLING OF A PHOTOVOLTAIC PANEL BASED ON THEIR ACTUAL MEASUREMENTS

J.A. Ramos Hernanz 1  J.M. Lopez Guede 2  I. Zamora Belver 3  P. Eguia Lopez 3
E. Zulueta 2  O. Barambones 2  F. Oterino Echavarri 4

1. Electrical Engineering Department, University College of Engineering of Vitoria, University of the Basque Country (UPV/EHU), Vitoria, Spain, josean.ramos@ehu.es
2. Systems and Automatic Control Department, University College of Engineering of Vitoria, University of the Basque Country (UPV/EHU), Vitoria, Spain jm.lopez@ehu.es, ekaitz.zulueta@ehu.es, oscar.barambones@ehu.es
3. Electrical Engineering Department, Faculty of Engineering of Bilbao, University of the Basque Country (UPV/EHU), Bilbao, Spain, inmaculada.zamora@ehu.es, pablo.eguia@ehu.es
4. Electronic Technology Department, University of the Basque Country, Vitoria Gasteiz, Spain, f.oterino@ehu.es

Abstract- The objective of this paper is the realization of a computer model that simulates the behavior of a photovoltaic module for any value of irradiance and temperature. This will allow us to work with the photovoltaic module regardless of weather conditions. For its implementation we use two computer programs, Excel and Matlab. In Excel, we will adapt our data and Matlab will make the model itself. The model will be made from experimental and technical data of the commercial panel Mitsubishi PV-TD185MF5. The data are taken randomly during a year. We have tried to collect as many combinations of irradiance and temperature as possible. The validity of this model is demonstrated by means of the implementation of IV and PV curves of the photovoltaic panel. The precise knowledge of these curves provides insight into the module operation and adequacy of model.

Keywords: Photovoltaic Cell, PV-IV Curves, Modeling, Simulation, Matlab.

I. INTRODUCTION

Photovoltaic solar energy is a clean and renewable energy, with a long life and high reliability. Because of its high cost and low efficiency its energy production is lower than other energy sources. The ideal solar cell, theoretically, can be modeled as a current source in anti-parallel with a diode, as Figure 1. The direct current, generated when the cell is exposed to light, varies linearly with solar radiation. An improvement of the model includes the effects of a shunt resistance and another one in series. The use of simple models provides sufficient accuracy to analyze the behavior of the solar cell, and has proven been effective in most cases.

According to [1-11] and based on the equivalent circuit of a photovoltaic panel, in Figure 1, the relationship between the voltage (V) and current (I) provided by a module, as shown in Equation (1).

\[ I = I_L - I_S \left( \frac{(V + IR_S)}{e^{\alpha N_s TN} - 1} - \frac{V + IR_S}{R_L} \right) \]  

In this case composed of \( N_s \) cells in series. Although this equation could also be used to represent a single cell \( (N_s = 1) \).

To determine the behavior of the solar panels it is necessary to know the voltage and amperage provided by different operating states in which they may be encountered.

For this we have developed the IV and PV curves, Figure 2, from Equation (1). The characteristic curve is called to the relationship between the electrical current (power) that provides the cell and the potential difference between its ends, for a given radiation intensity, when the load is been changing. These curves also depend on the temperature at which the cell is.
A. Photovoltaic Panel to Be Developed

In order to apply these concepts to developments of a solar cell model, the Mitsubishi PV-TD1185MF5 PV module has been chosen for modelling. This module has 50 series connected polycrystalline cells. The key specifications are shown in Table 1.

Table 1. Key specifications of the Mitsubishi PV Panel

<table>
<thead>
<tr>
<th></th>
<th>PV-TD185MF5</th>
</tr>
</thead>
<tbody>
<tr>
<td>Cell type</td>
<td>Polycrystalline Silicon</td>
</tr>
<tr>
<td>Maximum Power [W]</td>
<td>185</td>
</tr>
<tr>
<td>Open Circuit Voltage $V_{OC}$ [V]</td>
<td>30.60</td>
</tr>
<tr>
<td>Short circuit Current $I_{SC}$ [A]</td>
<td>8.13</td>
</tr>
<tr>
<td>Voltage, max power $V_{MPP}$ [V]</td>
<td>24.40</td>
</tr>
<tr>
<td>Current, max power $I_{MPP}$ [A]</td>
<td>47.5 ºC</td>
</tr>
<tr>
<td>Normal operating cell temperature (NOCT)</td>
<td>47.5 ºC</td>
</tr>
</tbody>
</table>

The performance of solar cell is normally evaluated under the standard test condition (STC), where an average solar spectrum at AM 1.5 is used, the irradiance is normalized to 1000 W/m², and the cell temperature is defined as 25 ºC.

II. DEVELOPED MODEL

To make this model, experimental values of voltage and current of solar modules are need. These values have been obtained from measurements in the solar module Mitsubishi PV-TD1185MF5. Data were obtained from the schema shown in Figure 3 since August, 2013 until the present day. For the configuration of the elements Sineax CAM and TV809 two programs (CB-Manager and TV800 plus) have been needed. In these programs are chosen the magnitudes to be measured and the conversion to perform.

A. Experimental Data

The scheme of Figure shows the manner of connecting the elements for the acquisition of experimental data, Figures 3 and 4.

CB-Manager integrates all the functions necessary for configuring the SINEAX CAM and for displaying the measured values.

The elements used are:

1. Sineax CAM: It is designed for long-term measurements in industrial installations or electrical distribution networks. It allows a continuous measurement and recording of measurement data. The interface I/O can be configured according to the requirements. The selected parameters to register are irradiance, temperature, voltage and current. With its unique combination of hardware and software modules this measuring device provides a solution for each measurement task. The adaption to this task is performed quick and easy by means of the CB-Manager software.

2. TV809: Its functions are, to isolate electrically the input and output signals, amplifying and/or converting the signal level or type (current or voltage) of the input DC signals. Measured variables and measuring ranges are programmed with the help of a PC. The functions of the two elements in our scheme are, to convert the voltage and current of the module in a 4-20 mA current proportional to the input of SINEAX CAM.

3. Irradiance sensor (Si-420TC-T-K): It is a pattern cell. This element will provide irradiance and temperature of the system throughout the duration of the measurement. The measurement time for this test will not be long. When
the sensor acquires working temperature, these two values will have very little variation, therefore they will be assumed constant for the realization of the IV and PV characteristic curves.

4. Current clamps: Chauvin Arnoux PAC12: The PAC12 can measure direct currents provided by the solar module. Providing a voltage proportional to the measured current. Later another TV809 will be needed to convert this tension in another proportional current, which is measured with the SINEAX CAM.

B. Data Processing
The measured data are saved in TXT files. After some minor modifications, all these files are opened as a single file in Excel as Figure 5.

In Excel the values of temperature and irradiance are rounded as follows:
=REDOND.MULT(Temperature;10)
=REDOND.MULT(Irradiance;50)

With the temperature data are formed five data groups: Curves 50º, 40º, 30º, 20º and 10º C. Subsequently, each of these groups is arranged, depending on the irradiance. Forming other subgroups: 1000, 900, 800, 700, 600, 500, 400, 300, 200 and 100 W/m².

With this, we have groups of curves for different values of irradiance to different types of temperature as Figure 6.

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III. EXPERIMENTAL DESIGN
Experimental data pairs (V, P) are loaded in Matlab
>> A=load('dates.txt');
>> voltage=A(:,1);
>> power=A(:,2);

Open the Curve Fitting Tool (cftool). Select X data (Voltage) and Y data (Power). There are different fit options. For example, polynomial, a cubic polynomial, ...

A polynomial curve 5º degree will be chosen. This is done for all the curves. Thereby, polynomial equations 5º degree will be obtained from the experimental data.

In Excel, it apply to these equations, values of voltage from 0 to 30 (from 0.5 to 0.5) yielding the curves as shown in Figure 7.

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IV. SIMULATION RESULTS
With these same equations, is generated in Matlab a file able to show the desired PV curve, from values of temperature and irradiance previously chosen as Figure 8.

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It have also been made other models in Matlab. For example, one is able to provide a characteristic curve and not the full range of curves. Also based on the same data there is another model in Simulink.
V. CONCLUSIONS

The main advantage is that this model has been developed from actual experimental data from the solar module. In the results are included all losses.

However it is not always possible to obtain this information because it may be expensive or because you cannot have means or time to get them. It is therefore very interesting to have simulation models to work in any weather condition.

The main disadvantage of this model is that it is very difficult to obtain all the necessary values. The data obtained are dependent on the weather and are only valid for a particular panel. For each panel, you have to repeat all measures.

For example, in this model the curves are widespread only five temperatures, instead of having the whole temperature range.

Another disadvantage is that it takes a long time to take the experimental data.

NOMENCLATURES

\( I_{sc} \): Short-circuit current
\( I_{mpp} \): Current at the maximum-power point
\( I_{L} \): Light-generated current
\( I_{D} \): Diode current
\( I_{R} \): Diode reverse saturation current
\( I_{Rsh} \): Current through the shunt resistance
\( I_{L} \): Irradiation
\( V_{oc} \): Open-circuit voltage
\( V_{mpp} \): Voltage at the maximum-power point
\( P_{mpp} \): Power at the maximum-power point
\( R_{S} \): Series resistance
\( R_{Sh} \): Shunt resistance
\( q \): Electron Charge constant, 1.6 \times 10^{-19} \text{ C}
\( n \): emission coefficient, ideality factor. (Si = 1.2)
\( a \): Diode ideality constant.
\( k \): Boltzmann’s constant.
\( T \): Cell temperature
\( N_{S} \): Number of cells in series

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REFERENCES


BIOGRAPHIES

Jose Antonio Ramos Hernanz was born in Vitoria Gasteiz, Spain, 1966. He received Bachelor degree in Electrical Engineering from University College of Engineering of Vitoria Gasteiz, Spain, in 1991 and Master degree in Industrial Organization Engineering from Faculty of Engineering of Bilbao, Spain in 2003 both belong to University of the Basque Country. Since 1991 he is working at University College of Engineering of Vitoria Gasteiz, Spain). He is Full Lecturer at Electrical Engineering Department of the same university. He was Academic Secretary of Department of Electrical Engineering at University of the Basque Country (10/1998-02/2002), and Vice-Dean of Educational Planning and Faculty at University College of Engineering of Vitoria-Gasteiz (11/2004-03/2009 and 2013- to date). His main research interests are electric power quality, photovoltaic energy, and bird protection on power lines.

Jose Manuel Lopez Guede was born in Eibar, Spain, 1976. He received the M.Sc. degree in 1999 and the Ph.D. degree in 2012, both in Computer Sciences from University of the Basque Country, San Sebastian, Spain. Since 2002, he is working at the same university. His current position is Assistant Professor at the Systems Engineering and Automatic Control Department at the University College of Engineering of Vitoria Gasteiz, Spain.
Inmaculada Zamora Belver received her Electrical Engineering and PhD degrees from the University of the Basque Country (Spain) in 1989 and 1993, respectively. She is currently a full time Professor and Dean in Department of Electrical Engineering (University of the Basque Country). Her research activities are concentrated in Electric Power Systems, Transients Simulation, Fault Analysis and Protection, Transmission Line Thermal Rating, Distributed Generation and Microgeneration.

Pablo Eguia Lopez was born in Bilbao, Spain, in July 1973. He received the M.Sc. and PhD degrees in Electrical Engineering from the University of the Basque Country, Spain, in 1998 and 2007. Currently, he is an Assistant Professor in the Department of Electrical Engineering at the University of the Basque Country. His research interests include power systems analysis and simulation, integration of distributed generation and power system protection.

Ekaitz Zulueta was born in Arrasate, Spain, 1975. He received the B.Sc. and M.Sc. degrees from University of the Basque Country, Vitoria Gasteiz, Spain, all in Electronic Engineering, and Automation in 1997 and 2000, respectively and the Ph.D. degree in Automatic Systems and Control from the same university, in 2005. Currently, he is an Assistant Professor at the System Engineering and Automation Department of the same university.

Oscar Barambones was born in Vitoria, Spain, 1973. He received the M.Sc. degree in applied physics, the Ph.D. degree in Control Systems and Automation, and the M.Sc. degree in Electronic Engineering, from the University of the Basque Country, Spain in 1996, 2000 and 2001, respectively. Since 1999 he has held several teaching positions at the Systems Engineering and Automation Department in the Basque Country University, where he is currently a Professor of Systems and Control Engineering. He is also the Vice Dean of Research and master in the University College of Engineering of Vitoria. He has more than 100 papers published in the main international conferences of the automatic control area, book chapters, and Journal Citation Report (Institute for Scientific Information) - indexed journals, has served as a Reviewer in several international indexed journals and conferences, and has supervised several Ph.D. theses. His current main research interests include the applied control of dynamic systems, particularly induction machines and its application to wind turbine systems.

Fernando Oterino Echavarri was born in Vitoria Gasteiz, Spain, 1970. He received the B.Sc. and the M.Sc. degrees from University of Basque Country, Spain all in Electronic Engineering, and Automation in 1998 and 2012, respectively. Currently, he is an Assistant Professor of University of Basque Country at the Electronic Technology Department.